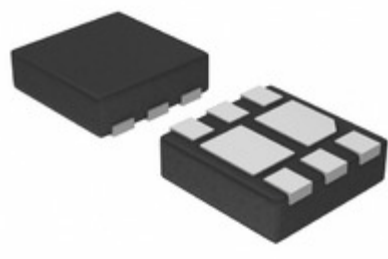


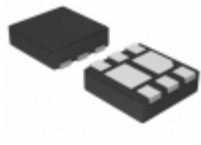

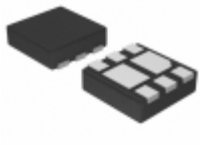
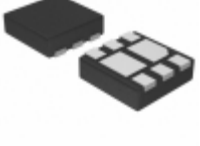
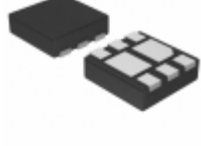
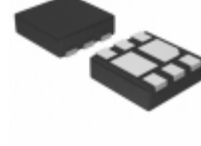
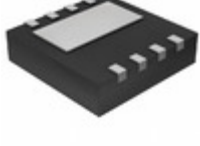
	NTLUD3A260PZTAG	
	Hersteller-Teilenummer:	NTLUD3A260PZTAG
	Hersteller / Marke:	AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung:	MOSFET 2P-CH 20V 1.3A UDFN6
	Datenblätter:	 NTLUD3A260PZTAG.pdf
	RoHs Status:	Bleifrei / RoHS-konform
	Lagerzustand:	New original, 99715 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	NTLUD3A260PZTAG
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET 2P-CH 20V 1.3A UDFN6
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	99715 pcs Stock
Serie	-
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	500mW
Verpackung / Gehäuse	6-UDFN Exposed Pad
Supplier Device-Gehäuse	6-UDFN (1.6x1.6)
Typ FET	2 P-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	1.3A
Rds On (Max) @ Id, Vgs	200 mOhm @ 2A, 4.5V
VGS (th) (Max) @ Id	1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	4.2nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	300pF @ 10V
Verpackung	Tape & Reel (TR)



















































NTLUD3A260PZTAG ist neu im Original, Suche NTLUD3A260PZTAG Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTLUD3A260PZTAG AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTLUD3A260PZTAG: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTLTS3107PR2G ON ON DFN-8</p>	 <p>NTLUD3191PZTBG AMI Semiconductor / ON Semiconductor MOSFET 2P-CH 20V 1.1A 6UDFN</p>	 <p>NTLTF4156NT ON ON QFN</p>	 <p>NTLUD3191PZTAG AMI Semiconductor / ON Semiconductor MOSFET 2P-CH 20V 1.1A 6UDFN</p>
 <p>NTLUD3A50PZTAG AMI Semiconductor / ON Semiconductor MOSFET 2P-CH 20V 2.8A UDFN</p>	 <p>NTLUD3A50PZTBG AMI Semiconductor / ON Semiconductor MOSFET 2P-CH 20V 2.8A UDFN</p>	 <p>NTLUD4C26NTBG AMI Semiconductor / ON Semiconductor MOSFET 2 N-CH 30V 9.1A 6UDFN</p>	 <p>NTLTD7900ZR2G AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 20V 6A 8MICRO</p>

heiße Teile

Mehr

 A8295SESTR-T	 AM27C2048-90DC	 BAT54WS-GS18	 CC0603JRNPO7BN151	 DC213-B1
 FAN5230QSC	 GRM1555C1H4R9BA01D	 ISL61851DCBZ-T	 KA2800A1400V	 MASWSS0202TR-3000
 MAX5160MEUA+T	 MAX5900ACEUT+T	 MCD250-12io8	 MG30G2YL1	 NTLGD3502NT1G
 D NTLGD3502NT2G	 NTLJ3113PT1G	 NTLJD2105LTBG	 NTLJD3115PT1G	 NTLJD3115PTAG
 NTLJD3119CT1G	 NTLJD3119CTAG	 NTLJD3119CTBG	 NTLJD4116NT1G	 NTLJF3117PT1G
 NTLJF4156NT1G	 NTLJF4156NTAG	 D NTLJS2103P	 NTLJS2103PTAG	 NTLJS2103PTBG
 NTLJS3113P	 D NTLJS3113PT1G	 NTLJS3113PTAG	 NTLJS3A18PZTWG	 NTLJS4114NT1G
 NTLJS4114NTAG	 NTLLED4901NF	 NTLLED4901NFTWG	 NTLTD7900NR2G	 NTLTD7900ZR2
 NTLTD7900ZR2G	 NTLUD3A50PZTAG	 NTLUF4189NZTAG	 D NTLUS3A18PZTAG	 NTLUS3A40PZTAG
 NTLUS3A40PZTBG	 NTLUS3A90PZTAG	 NTLUS4930NTAG	 UCC5680PW24	 UNR52A1G0LS0+

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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